

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
30V	$7m\Omega$ @ $V_{GS} = 10V$	60A		
30 V	$11m\Omega @ V_{GS} = 4.5V$	00A		

Features

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Description

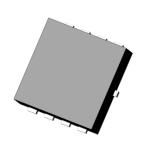
This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

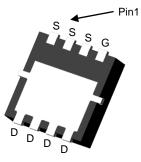
- Power Management Functions
- Analog Switch

Mechanical Data

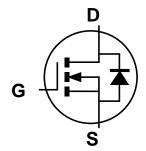
- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)







Bottom View



Equivalent Circuit

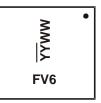
Ordering Information (Note 4)

Part Number	Case	Packaging
DMT3006LFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel
DMT3006LFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FV6 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current, $V_{GS} = 10V$ (Note 7) Steady $T_C = +25^{\circ}C$ State $T_C = +70^{\circ}C$			I _D	60 45	Α
Maximum Body Diode Forward Current (Note 7)	Is	2	Α		
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%	I _{DM}	90	Α		
Pulsed Drain Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)			I _{SM}	90	Α
Avalanche Current (L = 0.1mH) (Note 8)			I _{AS}	24	Α
Avalanche Energy (L = 0.1mH) (Note 8)			E _{AS}	29	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	1.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	130	°C/W	
Total Power Dissipation (Note 6)		P_{D}	2.0	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	63	°C/W	
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	2.9	C/VV	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}		_	1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	1	_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			5.6	7	mΩ	$V_{GS} = 10V, I_D = 9.0A$	
Static Dialii-Source Off-Resistance	R _{DS(ON)}		8.0	11	11122	$V_{GS} = 4.5V, I_D = 8.5A$	
Diode Forward Voltage	V_{SD}		0.70	1.2	٧	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}		1,155	_		V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	456	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	72	_			
Gate Resistance	R_g		1.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg		8.4	-	nC Vpp = 15V, lp = 9A		
Total Gate Charge (V _{GS} = 10V)	Q_g		16.7	-			
Gate-Source Charge	Qgs		2.2	1	110	$V_{DD} = 15V, I_D = 9A$	
Gate-Drain Charge	Q_{gd}		3.5	_			
Turn-On Delay Time	t _{D(ON)}		3.5	_			
Turn-On Rise Time	t _R		5.5	_	no	$V_{DD} = 15V, V_{GS} = 10V,$ $R_g = 3\Omega, I_D = 9A$	
Turn-Off Delay Time	t _{D(OFF)}	_	13.5	_	ns		
Turn-Off Fall Time	t _F	_	4.6	_			
Reverse Recovery Time	t _{RR}	_	19.3	_	ns	1 1 5 4 4 4 100 1 4 5	
Reverse Recovery Charge	Q _{RR}		8.6	_	nC	$I_F = 1.5A$, di/dt = 100A/ μ s	

^{5.} Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).

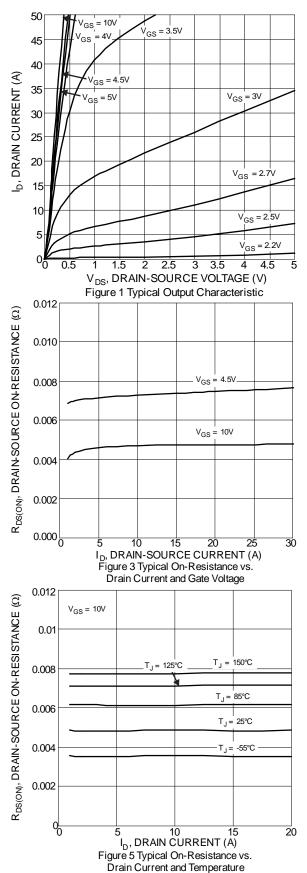
^{8.} I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

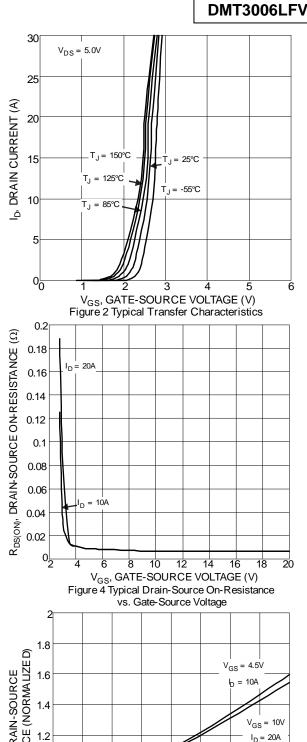
^{9.} Short duration pulse test used to minimize self-heating effect.

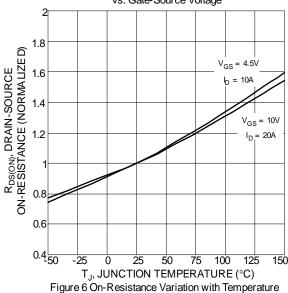
^{10.} Guaranteed by design. Not subject to product testing.



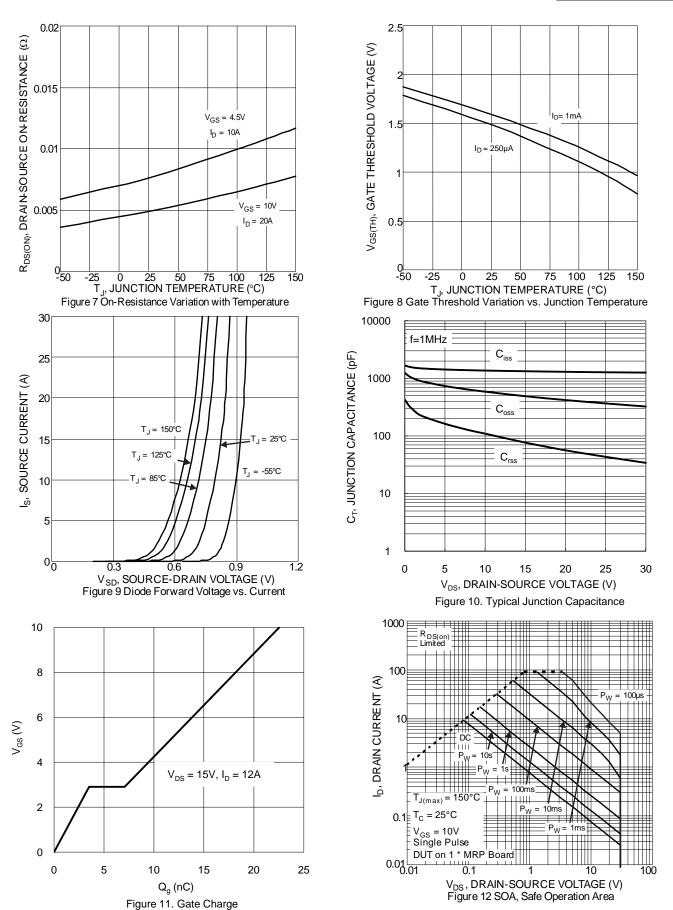




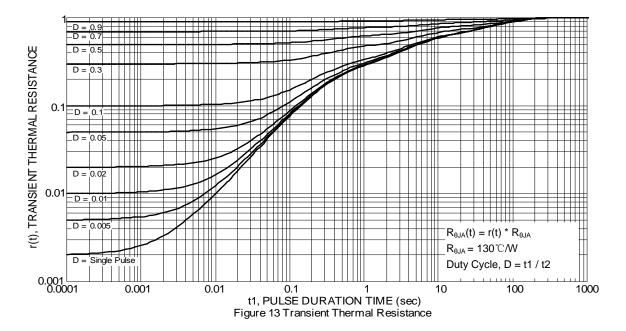










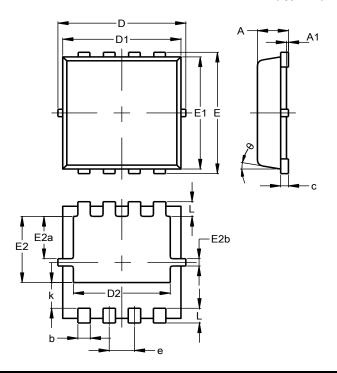




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

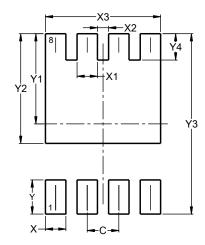


PowerDI3333-8						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Υ	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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